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Mac.1. Field of the Invention This invention relates to a semiconductor device and a method of manufacturing the same, and more particularly to a SONOS-type nonvolatile memory device and a method of manufacturing the same. 2. Description of the Related Art As a nonvolatile memory cell, a SONOS-type cell, which is based on an Oxide-Nitride-Oxide (ONO) film structure, is widely used for a nonvolatile memory. However, the SONOS-type nonvolatile memory cell has a problem in that the memory cell size is large. In order to solve this problem, there has been proposed a memory cell in which a tunnel insulating film between a gate electrode and a charge accumulation region is formed of an ONO film structure (hereinafter referred to as a SONOS-type memory cell) (for example, refer to U.S. Pat. No. 6,011,725). Here, the above-mentioned SONOS-type memory cell will be described. FIG. 14 is a plan view showing a prior art SONOS-type memory cell. As shown in FIG. 14, the SONOS-type memory cell includes a control gate electrode 12, which overlaps a source region 14 and a drain region 16 with a channel region (not shown) therebetween, and a bit line 8, which is connected to the drain region 16. Further, an ONO film 26 is located between the control gate electrode 12 and the channel region. The ONO film 26 includes a bottom oxide film 18, a tunnel insulating film 20 and a top oxide film 22. Here, the ONO film 26 is formed of an ONO film. The ONO film has a three-layered structure constituted of a bottom oxide film, a tunnel insulating film and a top

oxide film, in order from the bottom side. The ONO film 26 is formed by applying the three-layered ONO film onto a substrate and then removing the portion of the ONO film, which is located between the control gate electrode 12 and the drain region 16, by etching. Here, the bottom oxide film 18 is formed of an oxide silicon film, the tunnel insulating film 20 is formed of a nitride silicon film, and the top oxide film 22 is formed of an oxide silicon film. Next, the method of forming the SONOS-type memory cell will be

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